

KSC2500

Medium Power Amplifier & Low Saturation



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{CBO}	Collector-Base Voltage	30	V
V _{CES}	Collector-Emitter Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	10	V
V _{EBO}	Emitter-Base Voltage	6	V
I _C	Collector Current (DC)	2	Α
I _{CP}	* Collector Current (Pulse)	5	Α
I _B	Base Current	0.5	Α
P _C	Collector Power Dissipation	900	mW
TJ	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

^{*} PW≤10ms, Duty Cycle≤30%

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I _{CBO}	Collector Cut-off Current	V_{CB} =30V, I_{E} =0			100	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB}=6V$, $I_{C}=0$			100	nA
BV _{CBO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	10			V
BV _{EBO}	Emitter-Base Breakdown Voltage	I _E =1mA, I _C =0	6			V
h _{FE 1}	DC Current Gain	$V_{CE}=1V, I_{C}=0.5A$	140		600	
h _{FE 2}		$V_{CE}=1V$, $I_{C}=2A$	70	200		
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =2A, I _B =50mA		0.2	0.5	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE}=1V$, $I_{C}=2A$		0.86	1.5	V
f _T	Current Gain Bandwidth Product	V _{CE} =1V, I _C =0.5A		150		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=1MHz		27		pF

h_{FE1} Classification

Classification	Α	В	С	D
h _{FE1}	140 ~ 240	200 ~ 330	300 ~ 450	420 ~ 600

Typical Characteristics

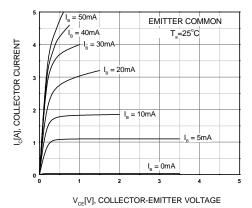


Figure 1. Static Characteristic

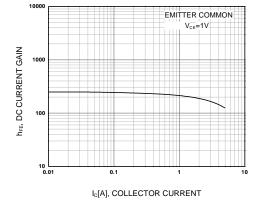


Figure 2. DC current Gain

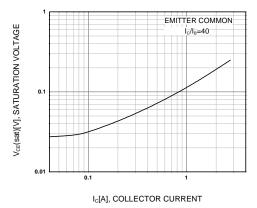


Figure 3. Collector-Emitter Saturation Voltage

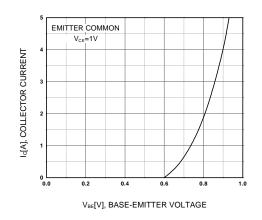


Figure 4. Base-Emitter On Voltage

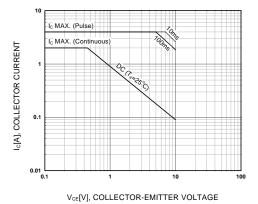
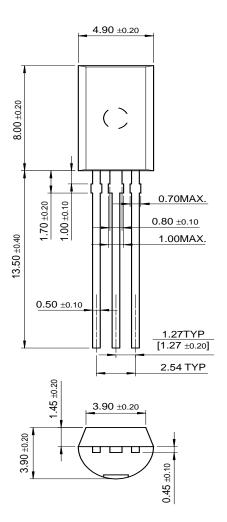


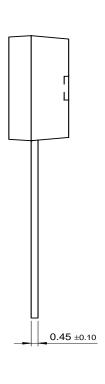
Figure 5. Safe Operating Area

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Package Demensions

TO-92L





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